

## IGBT MODULE ( Single-in-Line )

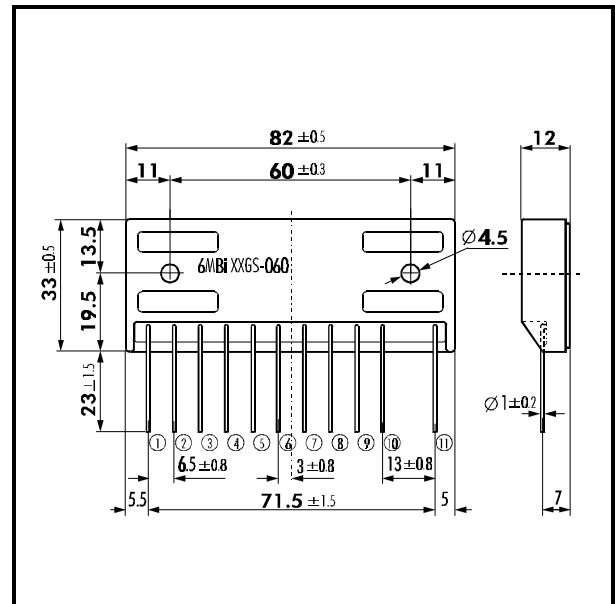
## ■ Outline Drawing

### ■ Features

- Square RBSOA
- Low Saturation Voltage
- Improved FWD Characteristic
- Minimized Internal Stray Inductance

### ■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls



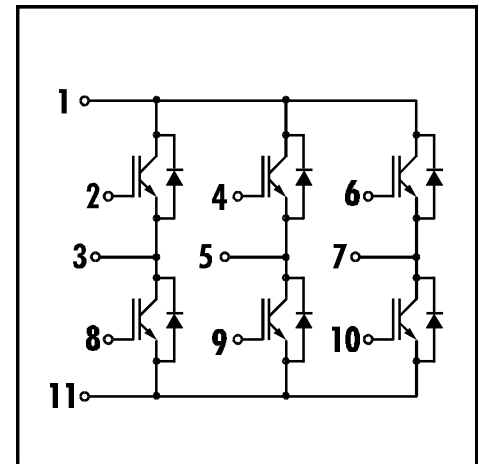
## ■ Maximum Ratings and Characteristics

### • Absolute Maximum Ratings ( T<sub>c</sub>=25°C )

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V <sub>CEs</sub>	600	V
Gate -Emitter Voltage	V <sub>GES</sub>	± 20	V
Collector Current	Continuous	I <sub>C</sub>	15
	1ms	I <sub>C PULSE</sub>	30
	Continuous	-I <sub>C</sub>	15
	1ms	-I <sub>C PULSE</sub>	30
Max. Power Dissipation	P <sub>C</sub>	60	W
Operating Temperature	T <sub>i</sub>	+150	°C
Storage Temperature	T <sub>stg</sub>	-40 ~ +125	°C
Isolation Voltage	V <sub>is</sub>	2000	V
Screw Torque	Mounting *1	1.7	Nm

Note: \*1:Recommendable Value; 1.3 ~ 1.7 Nm (M4)

## ■ Equivalent Circuit



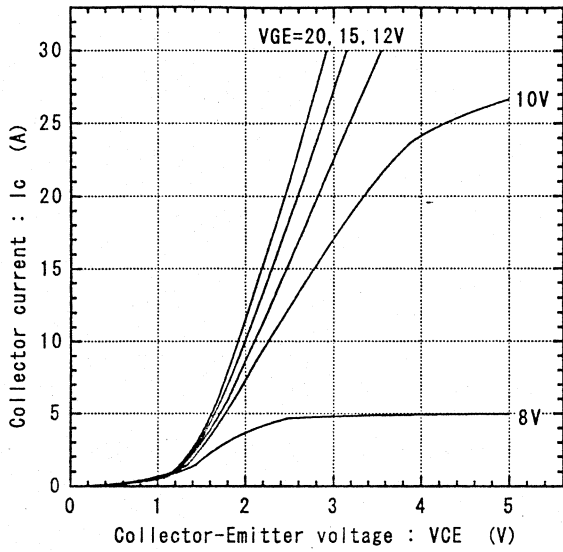
### • Electrical Characteristics ( at T<sub>j</sub>=25°C )

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I <sub>CEs</sub>	V <sub>GE</sub> =0V V <sub>CE</sub> =600V			1.0	mA
Gate-Emitter Leakage Current	I <sub>GES</sub>	V <sub>CE</sub> =0V V <sub>GE</sub> =± 20V			100	nA
Gate-Emitter Threshold Voltage	V <sub>GE(th)</sub>	V <sub>GE</sub> =20V I <sub>C</sub> =15mA	5.5		8.5	V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	V <sub>GE</sub> =15V I <sub>C</sub> =15A			2.8	V
Input capacitance	C <sub>ies</sub>	V <sub>GE</sub> =0V		975		pF
Output capacitance	C <sub>oes</sub>	V <sub>CE</sub> =10V		225		
Reverse Transfer capacitance	C <sub>res</sub>	f=1MHz		54		
Turn-on Time	t <sub>ON</sub>	V <sub>CC</sub> =300V			1.2	μs
	t <sub>r</sub>	I <sub>C</sub> =15A			1.0	
Turn-off Time	t <sub>OFF</sub>	V <sub>GE</sub> =± 15V			1.0	
	t <sub>f</sub>	R <sub>G</sub> =150Ω			0.35	
Diode Forward On-Voltage	V <sub>F</sub>	I <sub>F</sub> =15A V <sub>GE</sub> =0V			3.0	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =15A			300	ns

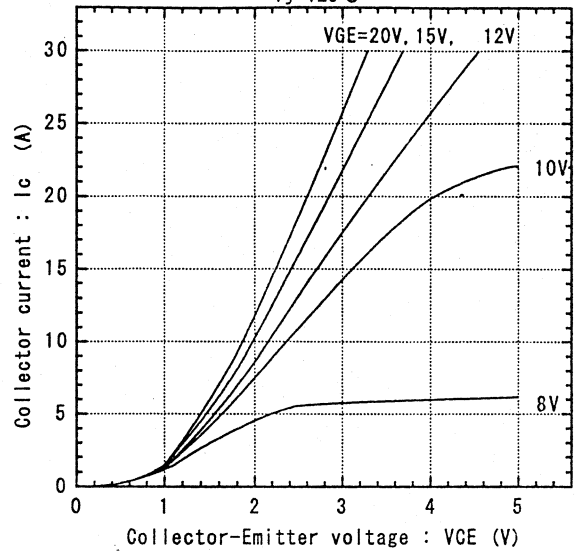
### • Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R <sub>th(f-c)</sub>	IGBT			2.08	°C/W
	R <sub>th(f-c)</sub>	Diode			3.00	
	R <sub>th(c-f)</sub>	With Thermal Compound		0.06		

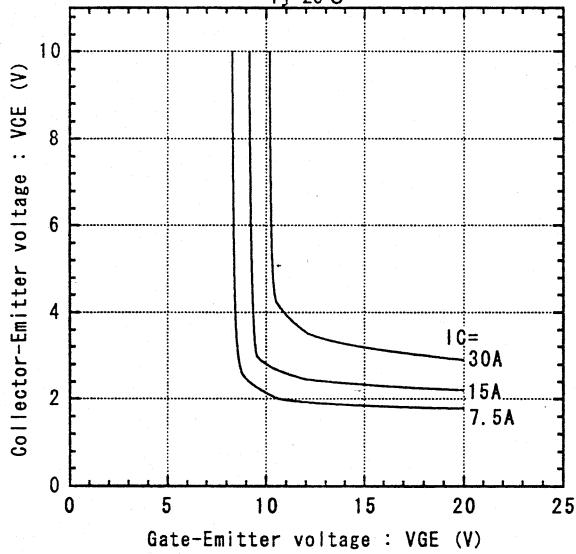
Collector-Emitter voltage vs. Collector current  
 $T_j=25^\circ\text{C}$



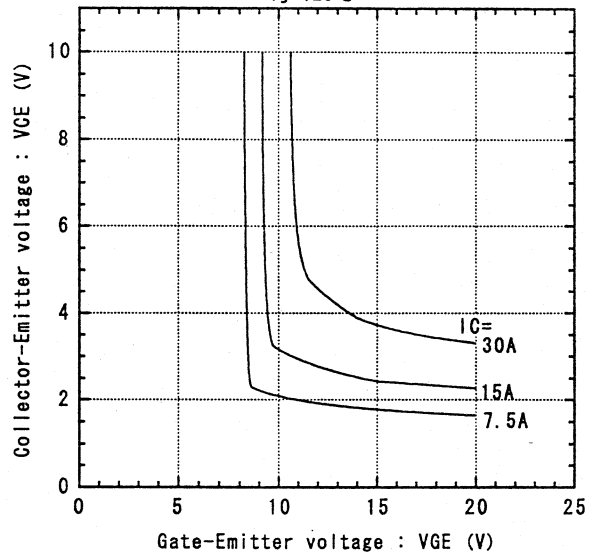
Collector-Emitter voltage vs. Collector current  
 $T_j=125^\circ\text{C}$



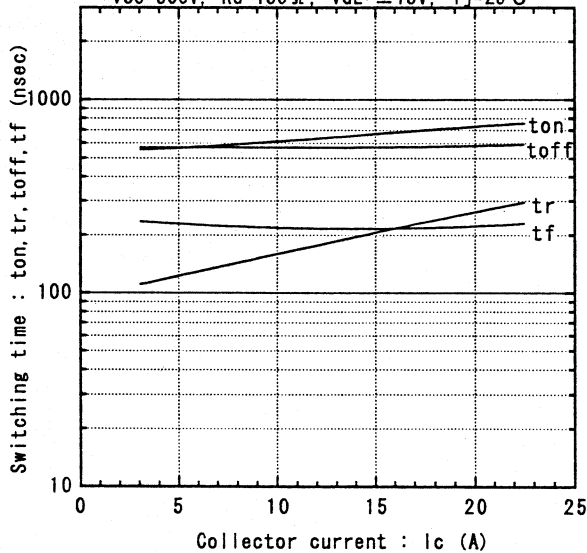
Collector-Emitter vs. Gate-Emitter voltage  
 $T_j=25^\circ\text{C}$



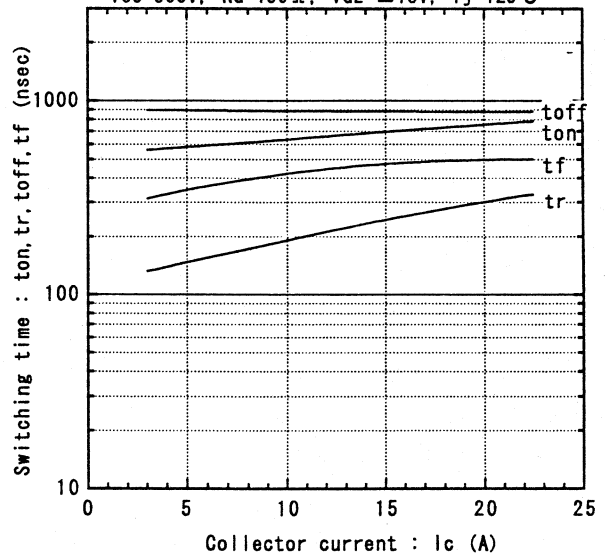
Collector-Emitter vs. Gate-Emitter voltage  
 $T_j=125^\circ\text{C}$

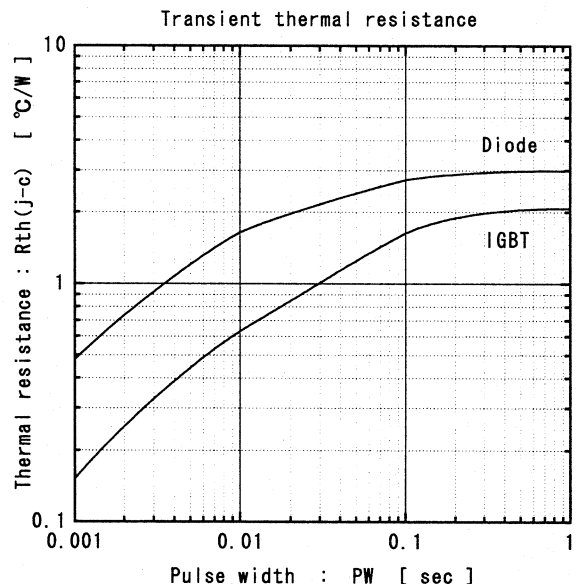
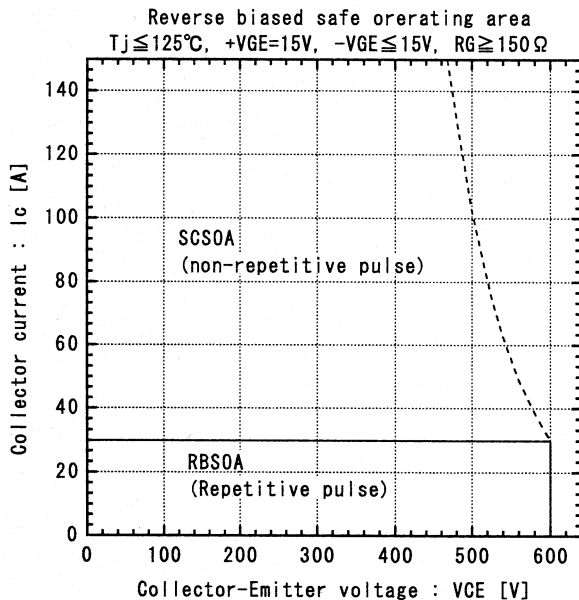
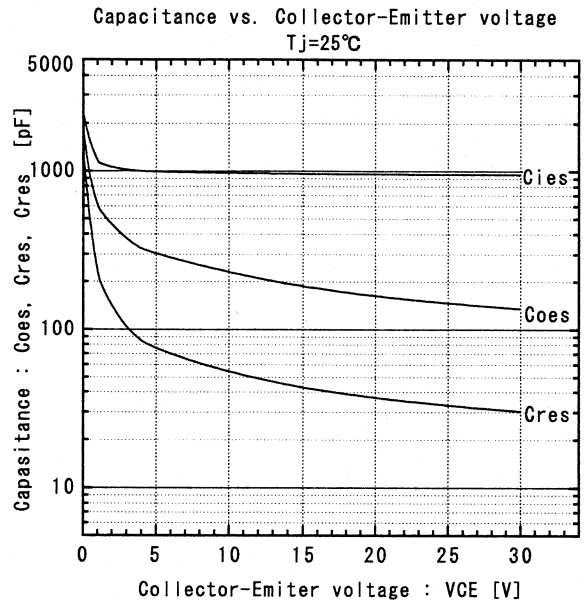
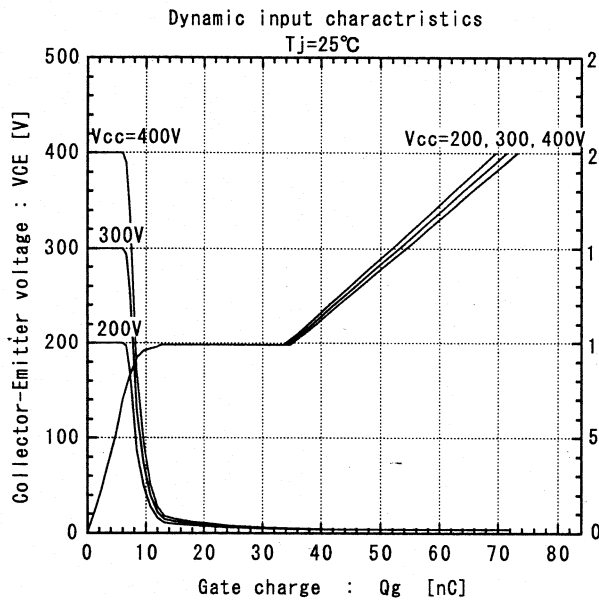
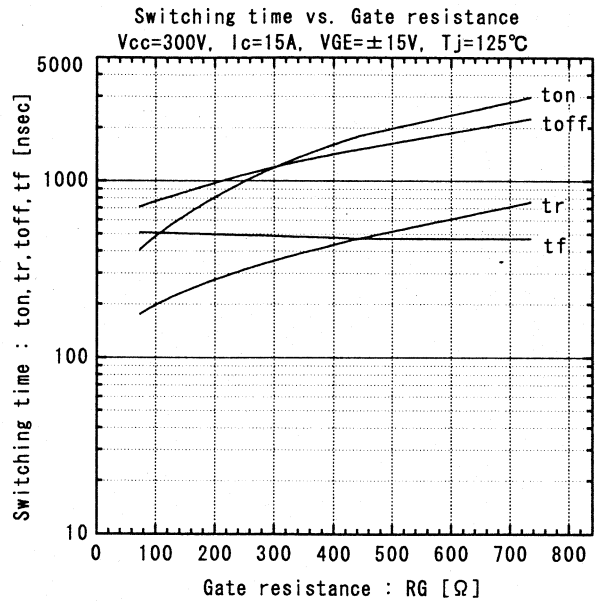
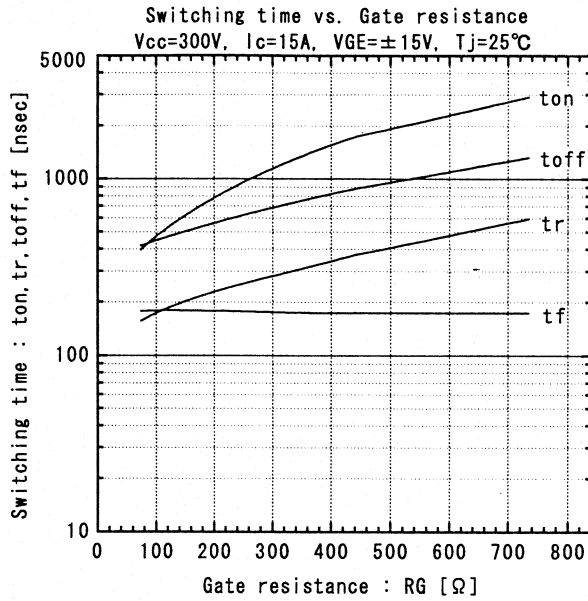


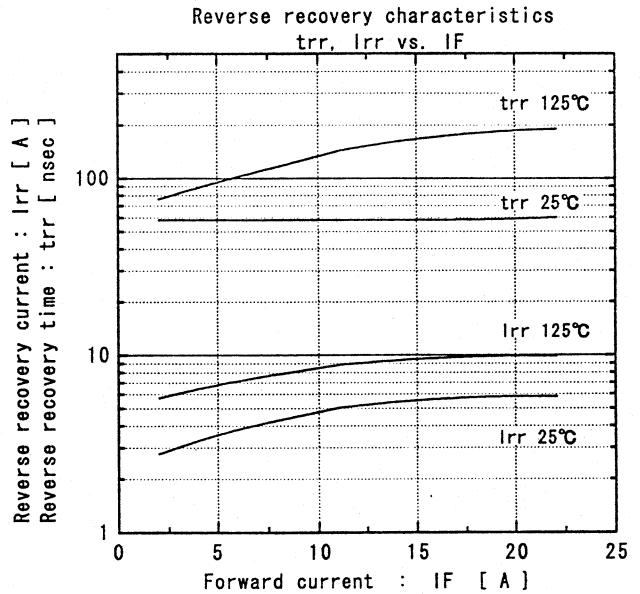
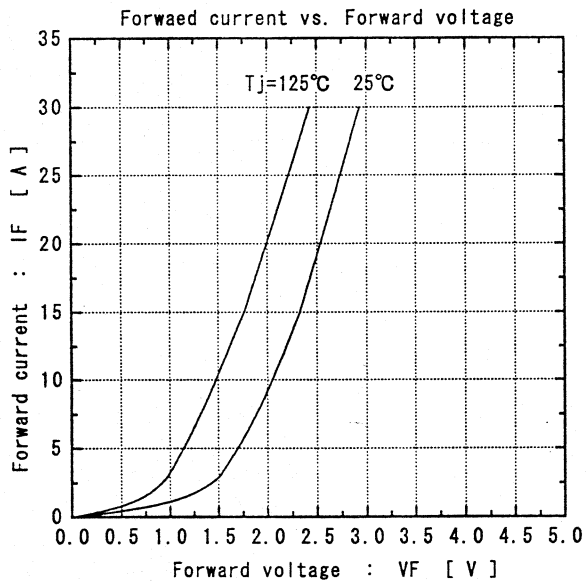
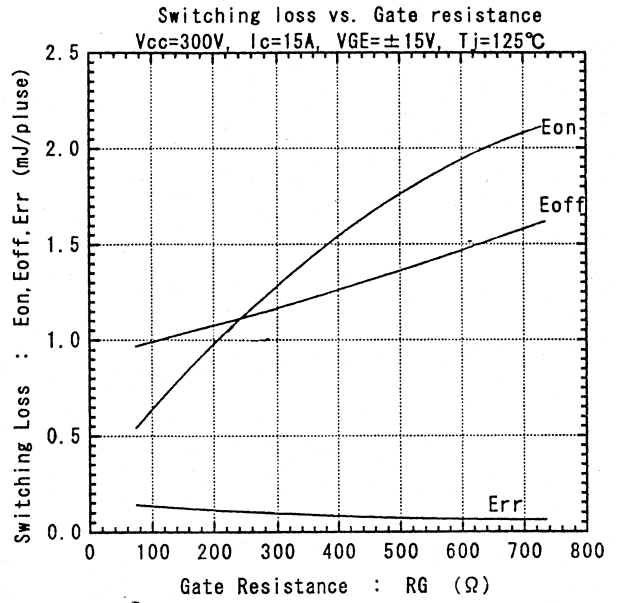
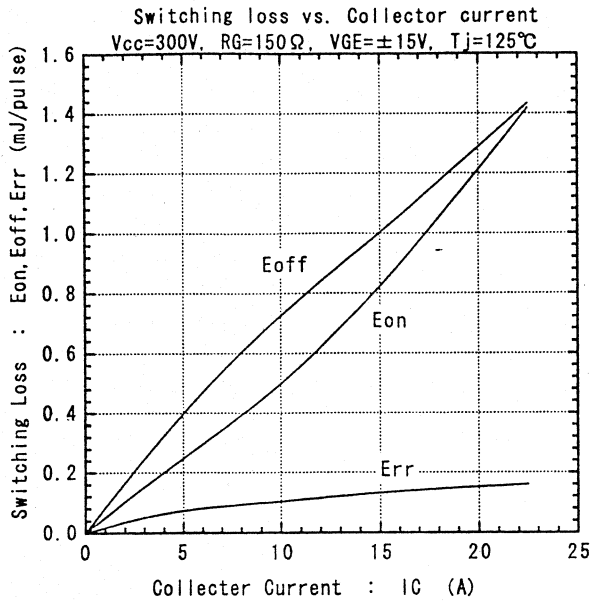
Switching time vs. Collector current  
 $V_{cc}=300\text{V}$ ,  $R_G=150\Omega$ ,  $V_{GE}=\pm 15\text{V}$ ,  $T_j=25^\circ\text{C}$



Switching time vs. Collector current  
 $V_{cc}=300\text{V}$ ,  $R_G=150\Omega$ ,  $V_{GE}=\pm 15\text{V}$ ,  $T_j=125^\circ\text{C}$







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